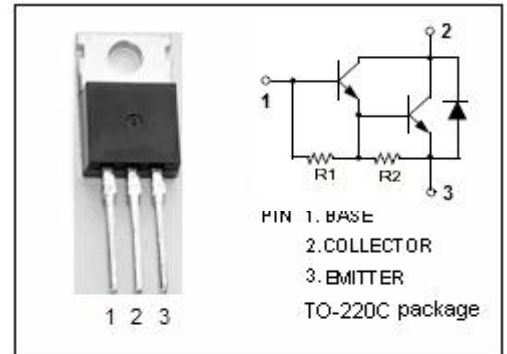


**DESCRIPTION**

- High DC Current Gain-  
:  $h_{FE} = 1000(\text{Min})@ I_C = 5A$
- Collector-Emitter Sustaining Voltage-  
:  $V_{CEO(\text{SUS})} = 100V(\text{Min})$
- Complement to Type TIP147T

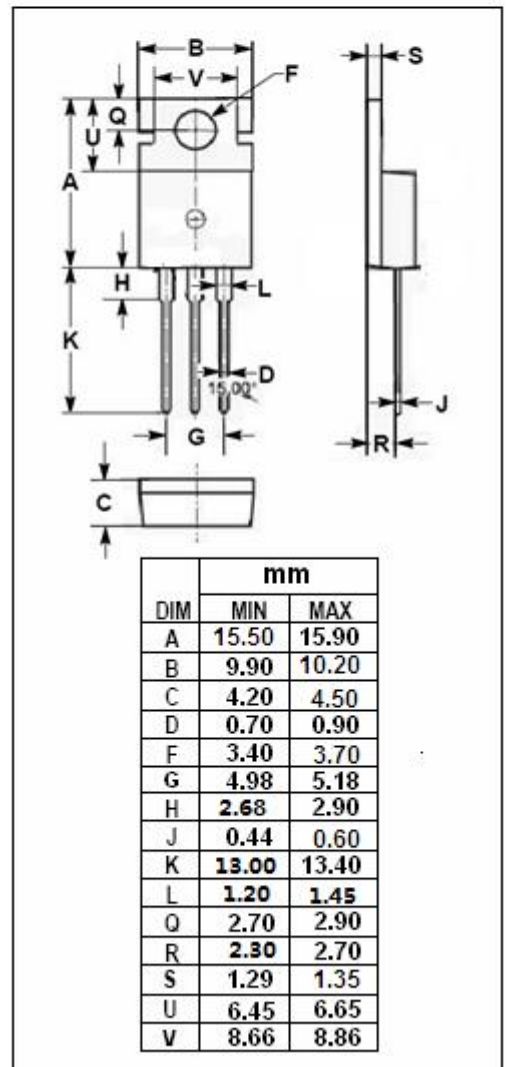
**APPLICATIONS**

- Designed for general purpose amplifier and low speed switching applications.



**ABSOLUTE MAXIMUM RATINGS(T<sub>a</sub>=25°C)**

SYMBOL	PARAMETER	VALUE	UNIT
V <sub>CB0</sub>	Collector-Base Voltage	100	V
V <sub>CEO</sub>	Collector-Emitter Voltage	100	V
V <sub>EBO</sub>	Emitter-Base Voltage	5	V
I <sub>C</sub>	Collector Current-Continuous	10	A
I <sub>CM</sub>	Collector Current-Peak	15	A
I <sub>B</sub>	Base Current- Continuous	0.5	A
P <sub>C</sub>	Collector Power Dissipation @T <sub>C</sub> =25°C	80	W
T <sub>j</sub>	Junction Temperature	150	°C
T <sub>stg</sub>	Storage Temperature Range	-55~150	°C



**THERMAL CHARACTERISTICS**

SYMBOL	PARAMETER	MAX	UNIT
R <sub>th j-c</sub>	Thermal Resistance, Junction to Case	1.56	°C/W

**ELECTRICAL CHARACTERISTICS**

T<sub>C</sub>=25°C unless otherwise specified

SYMBOL	PARAMETER	CONDITIONS	MIN	TYP.	MAX	UNIT
V <sub>CE0(SUS)</sub>	Collector-Emitter Sustaining Voltage	I <sub>C</sub> = 30mA, I <sub>B</sub> = 0	100			V
V <sub>CE(sat)-1</sub>	Collector-Emitter Saturation Voltage	I <sub>C</sub> = 5A ,I <sub>B</sub> = 10mA			2.0	V
V <sub>CE(sat)-2</sub>	Collector-Emitter Saturation Voltage	I <sub>C</sub> = 10A ,I <sub>B</sub> = 40mA			3.0	V
V <sub>BE(sat)</sub>	Base-Emitter Saturation Voltage	I <sub>C</sub> = 10A ,I <sub>B</sub> = 40mA			3.5	V
V <sub>BE(on)</sub>	Base-Emitter On Voltage	I <sub>C</sub> = 10A ; V <sub>CE</sub> = 4V			3.0	V
I <sub>CB0</sub>	Collector Cutoff current	V <sub>CB</sub> = 100V, I <sub>E</sub> = 0			1	mA
I <sub>CE0</sub>	Collector Cutoff current	V <sub>CE</sub> = 50V, I <sub>B</sub> = 0			2	mA
I <sub>EBO</sub>	Emitter Cutoff Current	V <sub>EB</sub> = 5V; I <sub>C</sub> = 0			2	mA
h <sub>FE-1</sub>	DC Current Gain	I <sub>C</sub> = 5A ; V <sub>CE</sub> = 4V	1000			
h <sub>FE-2</sub>	DC Current Gain	I <sub>C</sub> = 10A ; V <sub>CE</sub> = 4V	500			

Switching Times

t <sub>d</sub>	Delay Time	V <sub>CC</sub> = 30 V, I <sub>C</sub> = 5.0 A, I <sub>B1</sub> = -I <sub>B2</sub> = 20 mA; t <sub>p</sub> = 20 μ s Duty Cycle ≤ 20%		0.15		μ s
t <sub>r</sub>	Rise Time			0.55		μ s
t <sub>stg</sub>	Storage Time			2.5		μ s
t <sub>f</sub>	Fall Time			2.5		μ s